Polar in-plane surface orientation of a ferroelectric nematic liquid crystal: Polar monodomains and twisted state electro-optics

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We show that surface interactions can vectorially structure the three-dimensional polarization field of a ferroelectric fluid. The contact between a ferroelectric nematic liquid crystal and a surface with in-plane polarity generates a preferred in-plane orientation of the polarization field at that interface. This is a route to the formation of fluid or glassy monodomains of high polarization without the need for electric field poling. For example, unidirectional buffing of polyimide films on planar surfaces to give quadrupolar in-plane anisotropy also induces macroscopic in-plane polar order at the surfaces, enabling the formation of a variety of azimuthal polar director structures in the cell interior, including uniform and twisted states. In a π-twist cell, obtained with antiparallel, unidirectional buffing on opposing surfaces, we demonstrate three distinct modes of ferroelectric nematic electro-optic response: intrinsic, viscosity-limited, field-induced molecular reorientation; field-induced motion of domain walls separating twisted states of opposite chirality; and propagation of polarization reorientation solitons from the cell plates to the cell center upon field reversal. Chirally doped ferroelectric nematics in antiparallel rubbed cells produce Grandjean textures of helical twist that can be unwound via field-induced polar surface reorientation transitions. Fields required are in the 3-V/mm range, indicating an in-plane polar anchoring energy of \( \kappa_F \sim 3 \times 10^{-3} \text{ J/m}^2 \).

Nematic liquid crystals (LCs) are useful because of their facile collective response to applied fields and to surface forces (1). In a liquid crystal, the bulk response is the long-ranged deformation of a fluid, elastic field of molecular orientation, on which confining surfaces establish geometrical and topological structural constraints. In the realm of electro-optics, these two basic elements of LC phenomenology have been combined to create LC display technology (2), thereby enabling the portable computing revolution of the 20th century (3). In this development and until very recently, nematic electro-optics has been based on bulk dielectric alignment, in which a quadrupolar coupling to applied electric field induces polarization in a nonpolar LC to generate torque and molecular reorientation. Surface interactions employed to achieve desirable device structures are similarly quadrupolar, with common treatments such as buffing (4) or photo-alignment (5–8) described by the Rapini–Papoular (RP) model (9) and its variants.

Nematic LCs are fluids having internal long-range orientational ordering. In statistical mechanical terms, because the isotropic-to-nematic phase transition breaks orientational symmetry, it yields Goldstone modes in the nematic, describing spatial variation of the director, \( \mathbf{n}(r) \), the local average molecular orientation. Because of the full orientational symmetry of the isotropic phase, in the nematic phase the director has no globally preferred orientation and therefore the harmonic (elastic) energy cost of orientational variation of wavevector \( q \) decreases to zero as \( Kq^2 \) at long wavelengths, where \( K \) is the orientational (Frank) elastic constant. A bulk nematic sample can be oriented by providing an arbitrarily small force, for example an arbitrarily small applied electric or magnetic field, which couples to nematic orientation via quadrupolar dielectric or diamagnetic anisotropy. The nematic order is similarly infinitely responsive to boundary conditions imposed by surfaces on which there is orientational anisotropy. Because the nematic is a fluid, these conditions make it possible to put a nematic in a container, have it spontaneously anneal into a space-filling, three-dimensional (3D) director orientation structure dictated by the bounding surfaces, and have this structure respond in a predictable way to applied field. In practice, to be useful in applications, the surfaces and fields must be strong enough to eliminate defects and to produce sufficiently fast reorientations of the director.

A novel nematic LC phase (10–13) has recently been shown to be a ferroelectric nematic (NF) (14), offering a variety of opportunities to exploit LC field and surface phenomena in new ways. The ferroelectric nematic is a 3D liquid with a macroscopic electric polarization \( \mathbf{P}(r) \) (14). On the nanoscale, each molecular dipole is constrained to be nearly parallel to its molecular steric long axis, which translates macroscopically into a strong orientational coupling making \( \mathbf{P}(r) \) locally parallel to \( \pm \mathbf{n}(r) \), the local average molecular long axis orientation and uniaxial optic axis of the phase (14). The polarization thus endows the NF with coupling between \( \mathbf{n}(r) \) and applied electric field, \( \mathbf{E} \), that is linear and is dominant over the dielectric coupling at low \( \mathbf{E} \). The NF phase...

Significance

The devices of the portable computing revolution are being made possible by nematic liquid crystal display (LCD) technology. The optical changes viewed in a dynamic LCD image are based on reorienting molecules by coupling electronically generated electric fields to molecular dielectric anisotropy. This takes place in appropriate fluid electro-optic structures stabilized by nonpolar orientational coupling of molecules to surfaces. The recent observation of ferroelectric nematics having spontaneous macroscopic electric polarization density has introduced a much stronger coupling of electric field to molecular reorientation in nematics. This development opens opportunities for advanced electro-optics, but these will require polar control of molecular orientation by surfaces. The generation of polar-structured surfaces and their coupling to nematic polarity is demonstrated in this paper.


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exhibits self-stabilized, spontaneous polar ordering that is nearly complete (12, 14), with a polar order parameter, $P = \langle \cos(\beta) \rangle \sim 0.9$, where $\beta$ is the angle between a typical molecular dipole and the local average polarization density $P$. The resulting large spontaneous polarization ($P \sim 6 \mu C/cm^2$) enables field-induced nematic director reorientation and an associated electro-optic response with applied fields in typical cells as small as $-1 \text{ V/cm}$, a thousand times smaller than those used to reorient dielectric nematics.

The polar nature of the Nf also results in transformative changes in the interaction of the LC with bounding surfaces, a key aspect of nematic LC science and its potential for technology. Here, we demonstrate that structuring of the vectorial orientation distribution of a 3D volume of polar molecules can be achieved by controlling the polarity of its 2D bounding surfaces. In the simplest example, if the orientation of the preferred polarization is identical on the surfaces of the two parallel glass plates forming a cell, then the Nf volume polarization can be similarly oriented, that is, poled into a uniform orientation by the surfaces, without the need for an applied field.

Materials with spontaneous vectorial order such as ferromagnets and ferroelectrics minimize their energy by breaking up into domains of different orientation of their magnetization, $M(r)$, or polarization, $P(r)$, respectively, with these fields aligned locally parallel to the domain boundaries in order to minimize the energy of the internal and external magnetic or electric fields they produce. Intentionally disrupting this domain structure by applying an external field (“field poling”) is a key process in the use of such materials, e.g., putting an iron rod in a magnetic field to create a bar magnet (15), or actively reversing the polarization of a ferroelectric nanocrystal that serves as a data element in computer memories (16). Field poling of soft materials, such as the corona poling of chromophore-containing polymers to generate poled monodomains for nonlinear optical and electronic electro-optical applications, has been less successful because of the high fields required (17, 18). In ferroelectric nematics, in contrast, we find that polar aligning surfaces can be used to achieve uniform alignment of their nearly saturated bulk polarization, in the absence of an applied electrical poling field.

In a uniaxial (C Hispanic) ferroelectric nematic, the reduction in symmetry associated with the appearance of the bulk polarization, $P(r)$, yields a macroscopic coupling of $P$ to applied field $E$, with a corresponding bulk energy density $U_{PB} = -P \cdot E$. In materials where the net molecular dipole is nearly parallel to the steric long axis of the molecule, $P(r)$ is macroscopically constrained to be parallel to $\pm n(r)$ by an orientational energy of the form $U_{PB} = -\epsilon_{PNB} \langle n \cdot v \rangle^2$, where we define a unit vector polar director $v(r) = P(r)/P$. The energy density coefficient $\epsilon_{PNB}$ can be estimated as $\epsilon_{PNB} = k_B T \ln vol$ where vol is a molecular volume. If we apply a step change in the orientation of $P(r)$ at $x = 0$, then $n(r)$ will follow within a distance $|x| \sim \xi \sim (k_BT)\epsilon_{PNB}$, which will be of molecular dimensions. $v(r)$ and $\pm n(r)$ are therefore essentially locked together in orientation on the macroscopic scale, so that if a field is applied, the response is generally to reorient $n(r)$ by reorienting $P(r)$. An exception to this is the movement of pure polarization reversal (PPR) walls, which flip $P$ by 180° with no reorientation of $n$ (14).

Results

Polar Surface Anchoring. The intersection of $P(r)$ with a bounding surface deposits polarization charge on the surface, producing electric field-induced, long-ranged interactions with ionic and electronic charge, and with the Nf director (14). However, bounding surfaces are themselves always inherently polar, since structural variations along the surface normal, $x$, such as the number density or the polarization density of molecular components of the LC or the bounding phase, inevitably lack mirror symmetry about any interfacial plane normal to the surface. Such surface-normal polarity gives polar contributions to the local surface interaction energies of LCs (19–24), and in the Nf must be included in $W(0,\phi)$, the local energy/area of Nf–surface interaction that depends on $(0,\phi)$, the surface tilt and azimuthal orientation of $P(r)$ about surface normal $x$. A result is that at bounding surfaces, $P$ will always be nonzero and will have a preferred sign, so that if the polarization also has an in-plane component, $P$ will be tilted out of the yz-plane tangent to the surface. An exception to this would be a situation where the preferred $P$ depends on temperature, $T$, and changes sign at some $T$.

Additionally, the surface structure may have in-plane anisotropy. An RP-type surface treatment, such as bidirectional buffing or normal-incidence photoalignment, creates a surface structure that is azimuthally anisotropic and nonpolar with quadrupolar symmetry, meaning reflection symmetry about both the buffing direction and its in-plane normal (NONPOLAR case). This quadrupolar symmetry requires, in turn, that $n$ (described by the white, double-headed arrows in Fig. 1A) be parallel to the surface. The inherent surface polarity (vertical gray arrows in Fig. 1A) is, in this case, normal to this preferred orientation, and does not induce in-plane, polar symmetry-breaking of $n$. Interaction with a nematic director is given by a surface energy density $W_n(\phi)$, where here $\phi$ gives the in-plane azimuthal orientation between $n$ and the buffing direction, and $W_n(\phi)$ is quadrupolar [$W_n(\phi) = W_1(\phi) = W_{Q2}(\phi)$]. Following RP, we take $W_n(\phi) = W_n \sin^2 \psi$, where $W_n$ is a phenomenological coefficient (1, 9).

If, on the other hand, in-plane anisotropy is produced by unidirectional buffing along $z$, oblique photoalignment, or some other in-plane, polar treatment in the $(x,z)$ plane, then the surface orientation of a nematic director preferred by this treatment will not be parallel to the surface, but make some (pretilt) angle $0 < \psi < \pi/2$ with the surface plane. Coherent pretilt can be taken as direct indication that such surface treatment, which is procedurally apolar in the surface plane, has indeed broken apolar symmetry about the plane normal to the surface and the buffing direction. Such a surface is therefore in-plane polar with a nonzero polar surface energy $W_f$ giving equivalent surface energies for $n$ and $-n$ in the $Nf$ phase, but different surface energies for $P$ and $-P$ in the $Nf$. Such in-plane POLAR surface interactions are represented by the in-plane electric field $E$ and its in-plane normal ($\phi$ and $\psi$) is the in-plane azimuthal angle between $n$, the in-plane component of $n$, and the rubbing direction $z$, then the azimuthal term in the surface energy $W_n(\phi)$ must be reflection symmetric about the buffing direction [$W_n(\phi) = W_n(-\phi)$], and may be taken to have the form $W_n(\phi) = W_f(\phi) + W_\psi(\phi) = w_\psi \sin^2 \psi - 1/2 w_\psi \cos^2 \phi$, where $w_\psi$ is a phenomenological coefficient, as sketched in Fig. 1B.

The quadrupolar anisotropy of the LC surface energy density $w_Q$ has been widely studied experimentally with nematics (25). In the ferroelectric nematic phase, in contrast, $w_\psi$ is required by symmetry, but neither its magnitude nor its sign is known for any particular surface treatment. Here, we demonstrate the in-plane polar surface alignment of the Nf phase and obtain an estimate of the polar component of the anchoring energy. We show that such interactions are strong enough to enable full, polar control of the geometry of the nematic director in planar-aligned cells. We create twisted states of the nematic director of the sort pioneered by Mauguin (26) and later used in devices by Schadt and Helfrich (2), and apply in-plane electric fields to produce voltage-controlled optical changes, using much smaller fields and achieving a faster response than in dielectric nematics.

RMT34 (10) (isotropic $l \rightarrow 182^\circ \rightarrow$ Nematic $N \rightarrow 133^\circ \rightarrow$ Ferroelectric Nematic (NP)) was filled into glass cells with a gap of thickness $d$ separating the plates, one of which was patterned with ITO or gold electrodes spaced by $L$ for application of in-plane electric fields. Cells were studied optically using depolarized transmitted light microscopy (DTLM) with incident white light.
light, and their dynamic response measured using single-wavelength transmission of 632-nm HeNe laser light focused to a 30-μm-diameter spot. Cells either with random-planar glass surfaces, giving a Schlieren texture in the N phase, or with glass plates with buffered polymer alignment layers, giving planar monodomains upon cooling from the isotropic to the N phase, were used. We also used d = 3.5-μm and 4.6-μm-thick cells with unidirectionally buffered polymer alignment layers that favor alignment of the nematic director parallel to the buffering direction but with a coherent elevation of n above the surface plane by a small pretilt angle, ψ = 3° (27) (Fig. 1B). In this case, the apolar in-plane symmetry is broken (gray/white arrows in Fig. 1B) and the surface is potentially capable of in-plane polar alignment of the Nf phase, which we refer to simply as being POLAR. If the buffering is unidirectional and parallel on the two flat surfaces of a cell, then the surfaces will be termed SYNPOLAR, and if the unidirectional buffering is antiparallel they will be termed ANTIPOLAR.

Upon cooling, a NONPOLAR aligned cell with spatially uniform temperature through the N–Nf transition at −1 °C/min, we observe a texture of irregular domains extended locally parallel to n(r), first appearing on a submicron scale but then annealing over a roughly 2 °C interval into a pattern of lines, of low optical contrast and up to millimeters in length, that are also oriented generally along n(r) (14). These lines coarsen to form closed loops 10–200 μm in extent in some places, that have a distinctive

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**Fig. 1.** Cell structures of the Nf phase of RM734 under different planar alignment conditions, imaged using depolarized light transmission microscopy. (A and C) A NONPOLAR cell with bidirectional surface buffing gives planar alignment and no pretilt (director parallel to the surface). The cell surfaces are nonpolar, allowing the formation of domains of opposite ferroelectric polarization (d = 11 μm, T = 110 °C). The plot in A shows the corresponding orientational surface energy, W(φ), giving orientation along the rubbing direction. (B, D, and E) A cell with unidirectional parallel surface buffing gives POLAR planar alignment with pretilt of a few degrees (d = 4.5 μm, T ∼ 130 °C). The in-plane anchoring of n,P at each surface is polar, because the unidirectionality of the buffing breaks mirror symmetry normal to the surface plane and buffing direction, as evidenced by the coherent pretilt. The plot of W(φ) then shows a stable preferred well, shaded in pink, and a metastable well, shaded in orange, differing in energy by a. Cooling through the N–Nf transition with a temperature difference between the plates grows a polar-oriented Nf monodomain from the cooler plate (sketched in B, orange region in D). This cell is ANTIPOLAR, due to the antiparallel buffing on the two plates. As the cell is cooled further into the Nf phase, the orientation near the warmer plate eventually undergoes a surface reorientation transition to its lower-energy polar state, creating a π twist in the n–P field (E). This twist can be either left-handed (LH) or right-handed (RH), with 2π-twist walls separating these two states. The LH and RH states (purple) are optically degenerate when viewed between crossed polarizer and analyzer. (F) Schematic diagram of an antipolar (A), uniform director state, obtained when the cell is cooled homogeneously, the polar Nf phase growing in independently from both surfaces and eventually forming a pure polarization reversal (PPR) wall where the two oppositely oriented domains meet in the interior. (Scale bars: C, 20 μm; D, 200 μm.)
and characteristic lens shape, elongated along $n(r)$, as in Fig. 1A and C. These lines form boundaries where there is PPR (14) between ferroelectric domains with opposite sign of $\mathbf{P}$, which occupy roughly equal areas of the cell, i.e., showing little preference for a particular sign of $\mathbf{P}$. Application of a small, in-plane probe field enables visualization of the distinct orientations of $\mathbf{P}$, providing prime evidence for the ferroelectric nematic phase in RMT34. NONPOLAR alignment thus produces quality, uniform alignment of $\mathbf{n}$, which gives good extinction between crossed polarizer and analyzer.

We also probed the in-plane polar ordering and alignment effects of single surfaces in cells using the temperature gradient methods of Aryasova and Reznikov (28), who studied the structure and phase behavior of nematics in samples where a constant temperature difference, $\Delta T$, was maintained across the thickness of the cell. Upon cooling through the isotropic-to-nematic phase transition under these conditions, they found that the final nematic alignment obtained was predominantly that favored by the cooler cell surface, concluding that in a temperature gradient, the nematic phase appears first at the cooler surface and the I/N interface then moves as a quasi-planar sheet toward the warmer surface. In a cell with one plate coated with a rubbed polymer film, and the other with an untreated polymer film giving random-planar alignment, this form persists, with the optically uniform polar monodomain spreading to fill the cell area. However, if the temperature difference, $\Delta T$, is 0.1°C, any surface-polarization structure (31, 32), wherein splay of the $\mathbf{P}$ on semiconductor surfaces (33, 34), to the much smaller $\Delta T$, which is the twist elastic constant and $w$ is the relevant energy density coefficient (1). Applying a torque to the LC director induces a linear $\phi(x)$, which extrapolates to zero a distance $\lambda$ into the surface. Taking $K = 5$ mN and $\omega = 10^{-4}$ J/m² for typical rubbed polyimide alignment (25), we have $\lambda$ for the quadrupolar interaction $\lambda_{0} \approx 100$ nm so that orientational deformations in the few micro-\text{m} thick LC films studied here occur with $n(r)$ at the surface essentially fixed along one of the orientations preferred by the quadrupolar anchoring, and the fraction of the $\pi$ twist in the LC sustained by the surfaces is $\lambda(d + 2\Delta T)/\lambda_{0} \approx 1$. In other words, the torque transmitted by the bulk Frank elasticity and applied to the surfaces does not pull the orientation at each surface very far from that of the quadrupolar surface energy minima. In a cell with ANTIPOLAR surfacings, the $\pi$ twist on the surface are at $\phi = 0$ and $\phi = \pi$, with the minimum at $\phi = 0$ being of lower energy, and that at $\phi = \pi$ of higher energy only because of $W_{F}$ (Fig. 1B). The minimum at $\phi = \pi$ is therefore metastable, and, as $wP$ increases in magnitude as $T$ is lowered (due to the increasing magnitude of $\mathbf{P}$), a transition from $\phi = \pi$ to $\phi = 0$ becomes possible at the warmer surface. For a linear $\pi$ twist through the cell, the condition for this transition to occur is $wP > \lambda_{0} / 4d \approx 5 \times 10^{-6}$ J/m². This minimum required value of $wP$ is considerably smaller than the typical $wP$. In general, the nature of polar ordering of LCs along a surface normal varies widely, ranging from the perfect vectorial orientation of polar molecules, like 5CB on semiconductor surfaces (33, 34), to the much smaller induced polarization of mirror symmetric molecules on any surface. Ferroelectric chiral smectics exhibit polar surface interactions, including preferred polarization normal to the surface (35). A chiral smectic A exhibiting an electroclinic effect was found to have a normal component of polarization at the cell surface experiencing an effective surface field $E_{\perp} \approx 2 \mu$m normal to the surface (36). If the polar force is electrostatic, then the corresponding energy/area, $U_{p}$, depends on $l$, the thickness of the interaction volume, with $U_{p} \sim \mu_{p} E_{\perp} / l$. For the $\lambda_{0}$ phase, assuming an interaction volume of molecular dimensions, a similar estimate would give $U_{p} \approx 10^{-4}$ J/m² and $wP = U_{p} \pi \approx 10^{-3}$ J/m². Surface polarity can also induce polarization in the LC, leading to flexoelectric and order electric gradients in the vicinity of the surface (37–39).
Fig. 2. Orientational states of ANTIPOLAR and SYNPOLAR cells. Stable states in the $N_F$ phase induced by polar surface anchoring generated using unidirectional buffing, imaged using DTLM on cooling from $T = 135\, ^\circ C$ to $T = 125\, ^\circ C$. The red-to-blue arrow sequence represents the ferroelectric polarization orientation at increasing heights in the cell ($x = 0, d/4, d/2, 3d/4, d$, where $d = 3.5 \, \mu m$ in $A-E$ and $15 \, \mu m$ in $F-I$). The pink arrows indicate the azimuthal angular trajectory of $\phi(x)$ from the bottom to the top of the cell, which is also the light propagation direction. ($A$ and $B$) A $d = 3.5 \, \mu m$ ANTIPOLAR cell with a left-handed (LH) $\pi_T$ state (orange) growing into a uniform (U) state. The U state is dark between crossed polarizer and analyzer when $n$ is either parallel or normal to the analyzer, but shows light green/blue birefringence when rotated ($B$). The color of the $\pi_T$ state does not depend strongly on cell orientation. ($C$) Schematic diagram of the LH and RH $\pi_T$ states. In an ANTIPOLAR cell, with the field applied, $E$ and the white LC polarization vectors at the surfaces form a triad that is structurally chiral and changes handedness if $E$ changes sign, implying that field reversal will tend to flip the handedness of the $n,P$ structure. ($D$ and $E$) Decrossing the analyzer lifts the optical degeneracy of the LH and RH states, revealing their chirality and optical symmetry under simultaneous mirror reflection and reversal of the decrossing angle. The LH and RH states are separated by a $2\pi$-twist wall. ($F-I$) Uniform (U) $N_F$ state obtained on cooling a $d = 15 \, \mu m$ SYNPOLAR cell from the $N$ phase. With $n$ parallel to the crossed analyzer, the cell is dark ($F$ and $G$), showing quality, planar alignment of the director in both phases except near air bubbles (dark spots) in both phases. In the $N_F$ phase, the polarization is uniformly aligned, with no domains of opposite polarization observed anywhere in the cell. The sample is rotated through $45^\circ$ in $H$ and $I$. ($J$) Spontaneous transition of a pure polarization reversal (PPR) wall to a twisted state. In the absence of a gradient in $T$, the uniform director state has formed and grown independently from each surface, making a PPR wall near the cell center. The twist deformation at the PPR wall (yellow vectors) initially costs local twist Frank energy but the system eventually lowers the energy by effecting a topological transition that converts the PPR wall into uniform director twist between the cell plates. This transition is barrier-limited. When cooling an ANTIPOLAR cell in a temperature gradient, the PPR wall forms near the warmer surface. (Scale bars: 200 $\mu m$.)
Let us consider in more detail the events at the warmer surface of the ANTIPOLAR gradient cell. As the N–NF growth front approaches, as in Fig. 1B, the NF phase is replacing the N phase, which contacts the warmer buffered surface with its director lying along one of the quadrupolar minimum energy orientations. The NF director has the same orientation, but the locally polar orientation induced in the N phase by the surface does not match that of the approaching NF front: an N-phase gap with opposite signs of $\mathbf{P}$ on its two surfaces, a kind of PPR wall (14), is thus created and trapped, in a uniform director field. This geometry is at least metastable at temperatures near the N–NF transition. At lower temperatures, however, the orientation of $\mathbf{n}$ near the surface changes by $\pi$, transitioning to the other quadrupolar minimum so that the bulk matches $\mathbf{P}$ at the surface.

A possible mechanism for this transition is shown in Fig. 2J, where, for the purposes of illustration, we consider the temperature gradient along $\mathbf{x}$ being reversed, so that the NF grows from both surfaces and forms a PPR wall in the bulk. A simple topological transition can take place whereby appropriate twist deformation of $\mathbf{n} \rightarrow \mathbf{P}$ above and below the PPR wall reduces the magnitude of the component of $\mathbf{P}$ being reversed in the wall, leading to the replacement of the PPR wall with a twist wall, which then spreads along $\mathbf{x}$ to fill the cell, giving a uniformly twisted $\pi$T state. This is a barrier-limited transition because the initial twist must be substantial over the width of the PPR wall. If a gradient in $T$ is present, the process of eliminating the PPR wall formed near the warmer surface is essentially the same. Such a barrier-limited topological transition results in the heterogeneous nucleation and growth evident in Fig. 2. The sharp boundary between the uniform and $\pi$-twisted states is evidence for the metastability of the $\varphi = 0$ surface state at the warmer plate. The surface orientation transition between quadrupolar surface energy minima at $\varphi = 0$ and $\varphi = \pi$ is therefore solitonic in nature, very similar in structure to the surface-stabilized $\pi$ reorientation walls in chiral smectic ferroelectric LCs (surface-stabilized ferroelectric LCs) and similarly described by a double sine-Gordon equation (40).

The topological walls that separate the $\pi$T states are $2\pi$-twist ($2\pi$T) walls, illustrated in Fig. 2E. In the geometry of this cell, with the rubbing directions nearly parallel to the electrode edges, the polarization at midheight in the cell, $\mathbf{P}(x = d/2)$, is normal to the electrodes, in the $y$ direction for the left-handed $\pi$-twist state, and in the $-y$ direction for the right-handed $\pi$-twist state, and therefore parallel or antiparallel to the applied field, $\mathbf{E}$. The $2\pi$T walls consist of a $2\pi$-twist disclination line in the bulk $\mathbf{n}$ and $\mathbf{P}$ fields (Fig. 2 and SI Appendix, Fig. S2). If we consider just the treated ANTIPOLAR cell plates shown in Fig. 2C and the applied field, ignoring the LC, it is clear that this configuration is chiral, with a handedness that changes with the sign of field. This means that for a given sign of $E$, one of the $2\pi$T states is of lower energy than the other and therefore that the $2\pi$T walls can be moved by applying an electric field and will move in opposite directions for different sign of field, discussed further below in the context of SI Appendix, Fig. S2. The topological transition mediating the field-induced nucleation of the twist wall loops in an ANTIPOLAR cell is also barrier-limited, resulting, for example, in the heterogeneous nucleation of LH domains in a RH $\pi$-twisted cell shown in SI Appendix, Fig. S2. The $\pi$-twist walls persist upon heating through the N to NF transition, giving metastable LH and RH domains in the nematic, stabilized by the RP surface interactions (Fig. 4). The observation of $\pi$-twist walls is critical and unambiguous confirmative evidence for nematic ferroelectricity: The appearance of the spontaneous ferroelectric polarization of the NF, as a spontaneous uniform to $\pi$-twisted transition in an antiparallel buffered cell, is a uniquely ferroelectric nematic phenomenon, requiring not only macroscopic polari-

It should be clear from the preceding discussion that virtually any ferroelectric nematic structure in which there is twisted-planar reorientation of the n–P couple can be stabilized between plates by using aligning surfaces with bidirectional rubbing or monodirectional rubbing with appropriate pretilt. SI Appendix shows that this can be combined with chiral doping to control the relative stability of otherwise degenerate twisted states of different helicity, as in the case of twisted nematic devices (41). These textures are eventually replaced by that of the crystal phase on further slow cooling (at $T \sim 90^\circ C$). Quenching the NF from $T = 120^\circ C$ by dunking in room temperature water preserves these and the SYNPOLAR textures, discussed next, in glassy form.

In SYN POLAR aligned cells that are cooled homogeneously through the N–NF transition at $\sim 1^\circ C/min$, the well-aligned nematic monodomain observed in the N phase evolves into a uniform, polar monodomain of the NF phase (Fig. 2 F–I). These monodomains respond to in-plane fields as small as 1 V/cm applied normal to $\mathbf{P}$, as reported in ref. 14 for states of uniform $\mathbf{P}$, confirming bulk ferroelectric poling in the absence of an applied electric field.

**In-Plane Electro-Optics and Dynamics.** The field-induced orientational dynamic responses of planar-oriented cells described above can be classified into two principal types, one characteristic of field rotation (ROT), occurring when a component of $E$ appears in the direction normal to $\mathbf{P}$, and the other typical of field reversal (REV), occurring when the component of $E$ parallel to $\mathbf{P}$ changes sign. Assuming that $\varphi(x,t)$ varies only through the thickness of the cell, the bulk response to an in-plane applied field is governed by the dynamic torque balance equation, $\dot{\varphi}(x,t) = -P\varepsilon_0\sin\varphi + K\partial^2\varphi/\partial x^2$, where $\gamma$ is the nematic rotational viscosity. Simulations of the field-induced reorientation profiles, $\varphi(x,t)$, with fixed surfaces show these two distinct dynamic limits, ROT in Fig. 3D and REV in Fig. 3B.

The response of an initially uniformly twisted state to an in-plane field, $E$ applied at time $t = 0$ is shown in Fig. 3D. This simulation illustrates the ROT case, modeling the response of $\mathbf{P}$ that would follow a stepwise field rotation. Here, the applied field favors the orientation $\varphi = 0$, the initial orientation of $\mathbf{P}$ at the cell center, as in Fig. 2. The final, field-induced polarization state (black curve in Fig. 3D) is then subjected to field reversal (the REV case). For NONPOLAR cells (Fig. 1A), the polarization on the surfaces can be reversed independently, producing a mix of states for a left- and right-handed, uniformly twisted $\pi$-twist state. The resulting surface walls can be moved by field-induced torques (14). In general, then, there may be surface orientation transitions. In contrast, in the 3.5-$\mu$m-thick ANTIPOLAR cell, we do not observe field-induced polar surface reorientations. The surfaces stay in their POLAR preferred minima in these $E$-field experiments, and in this is also the case in the simulations presented in Fig. 3 B and D for an ANTIPOLAR cell, which have fixed surface orientations (we will see later that surface transitions can be induced when the sample is chirally doped, as illustrated in SI Appendix, Fig. S1).

In the following three sections, we consider ROT, domain wall, and REV reorientation. In all cases, the field variable $E$ refers to the magnitude of the field applied at the area of measurement: the probe laser spot in the ROT and REV cases; and in the electrode gap center for the domain dynamics DTLM images. In the gap center $E \sim V_{IN}/L$, where $V_{IN}$ is the voltage applied to the electrode gap, and $L \sim 1.5$ mm is its effective gap width, which is larger than the physical 1-mm gap because of the spread of field in the $x$ direction from the thin edges of the 2D electrodes.

**Field Rotation (ROT) Dynamics.** In the ROT response regime, $\varphi_0$, the initial angle between $\mathbf{P}$ and applied field $E$ is smaller in magnitude than $90^\circ$ ($|\varphi_0| \leq 90^\circ$) and the torque applied by the field, $T_E = -PE\sin\varphi$, tends to rotate $\mathbf{P}$ toward $\varphi = 0$. In the uniformly twisted starting state of Fig. 2D, this condition is obtained everywhere in the cell. Each element of the cell is effectively elastically decoupled from its neighbors, reorienting independently in the
applied field. The polarization responds in a continuous fashion without altering the topology, except for the surface regions at $\chi = 0$ and $d = d$ where the twist is squeezed into a thickness comparable to the deGennes field penetration length $\xi_E = \sqrt{K/\mu E}$ ~50 nm for $P = 6 \mu$C/cm$^2$ and an applied field $E = 40$ V/mm (14). At fields $E > 1$ V/mm, where the twist is confined to subwavelength thick surface regions, the optical transmission of this cell approximates that of a uniform birefringent slab, giving near planar alignment. A small DC bias sets the starting orientation of the sample, and the transmission $t(\ell)$ between crossed $P$ and $A$ is measured. The 10–90% response times are shown vs. field amplitude as the cyan squares in A. In weak applied fields, the response times decrease as $1/E$ and are used to determine $\gamma$. The deviation from $1/E$ dependence at intermediate $E$ is an effect of depolarization voltage at the electrodes, modeled as a leaky capacitor (black dots; see text).

In Fig. 3D, since $\xi_E < d$, the ferroelectric and viscous torques are dominant and the Frank elastic term can be dropped from the torque balance equation, yielding $\psi(\ell)/\partial \ell = -PE\sin(\psi(t)/2)\exp(-tPE/\sqrt{\mu L})$, where $\psi(t)$ is the starting angle between $P$ and $E = V_{\text{INT}}/L$. This is a particularly simple dynamic limit in which the ferroelectric/viscous torque balance independently controls the response of each element of length $d\ell = \xi_E$ of the sample, taking $(t)$ to be uniform in each such element with a starting value $\psi_0(t)$ (42). Thus, Fig. 3D also describes the homogeneous reorientation of samples with uniform $(t)$ starting with orientations in the range $-90^\circ < \psi_0(t) < 90^\circ$, including $\psi_0 = 45^\circ$ (cyan arrow). These simulations are thus applicable to the dynamical measurements of $(t)$ shown in Fig. 3E. For small $\psi_0$, the dynamics of $\psi(t)$ in this regime are exponential, with the characteristic relaxation time $\tau_E = \sqrt{\mu E}$. With these approximations, $\tau_E = \frac{\sqrt{\mu E}}{15}$, in which parts of the cell find themselves in a state of low-torque, unstable equilibrium ($\psi_0 = 0$), which remains until solitons, which form at the surfaces, pass by. The final state (red curve) has a 2-nm-thick wall at the cell center, which disappears by order reconstruction (cyan arrow), leaving the LH state (black curve). Arrival of the solitons at the cell center (white circle) produces local director reorientation that gives the transmitted intensity $I(t)$.

In the simulations of Fig. 3A, $E = 40$ V/mm and the cell thickness was initially taken to be $50$ nm. For $\xi_E > d$, the dynamics are more complicated, with the characteristic relaxation time $\tau_E = \sqrt{K/\mu E}$ ~50 nm for $P = 6 \mu$C/cm$^2$ and an applied field $E = 40$ V/mm (14). At fields $E > 1$ V/mm, where the twist is confined to subwavelength thick surface regions, the optical transmission of this cell approximates that of a uniform birefringent slab, giving near planar alignment. A small DC bias sets the starting orientation of the sample, and the transmission $t(\ell)$ between crossed $P$ and $A$ is measured. The 10–90% response times are shown vs. field amplitude as the cyan squares in A. In weak applied fields, the response times decrease as $1/E$ and are used to determine $\gamma$. The deviation from $1/E$ dependence at intermediate $E$ is an effect of depolarization voltage at the electrodes, modeled as a leaky capacitor (black dots; see text).

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To understand the high-field behavior, we consider that, while the large value of $P$ ensures a strong coupling of orientation to the applied field, it also produces ubiquitous space charge effects that may significantly slow the dynamics. In all of the cells with in-plane electrodes studied here, there is an effective thin, insulating barrier at the interface between the $N_F$ phase and the electrodes, a barrier that either has no polarization or in which the polarization is fixed in orientation. Such layers drop part of the applied field in maintaining the physical separation of free charge carriers from the polarization charge accumulated at the insulating interface with the ferroelectric LC. Such a layer is formed, for example, by the polymer films used for alignment, but even in the four-electrode cell shown in Fig. 3E, where there is no alignment layer and the interface is $N_F$/gold, the cell behavior indicates that such an insulating layer exists. If this layer has a capacitance $C$ farads per square centimeter, then the effective field in the above equation for $\psi_E(t)$ is reduced by the depolarization voltage $(P/C)\cos\psi_E(t)$, becoming $E = [V_{IN} - (P/C) \cos\psi_E(t)]/L$. Generally, these interfacial layers are not perfectly insulating, with free charge passing through to the polarization charge layer, in which case they can be modeled as a material of resistance $R \ \Omega \ \text{cm}^2$ in parallel with $C$ (a leaky capacitor). We then obtain for $(t)$:

*Fig. 4.* Low-field polarization reversal in an ANTIPOlar cell of RM734 at $T = 125^\circ \text{C}$. The cell thickness is $d = 3.5 \ \mu m$. In-plane ITO electrodes with a 1 mm gap are used to apply an electric field $E$ normal to the electrode edges. At the gap center, $E = (V_{IN}/L) \ \text{V/mm}$, where $V_{IN}$ is the voltage applied to the electrodes and $L \sim 1.5 \ \text{mm}$ their effective spacing due to the thin-electrode field geometry. The buffing directions are along the $z$ axis, which is oriented 3° from the electrode edges and therefore 93° from $V$. (A) Initial right-handed (RH) $\pi$T state in the absence of field. (B–H) Gradually increasing the applied voltage in the range $0 < V_{IN} < 0.4 \ \text{V}$ distorts the RH twist state and leads to the nucleation and growth of LH twist regions. The red-to-blue arrow sequences represent the ferroelectric polarization orientation at increasing heights in the cell ($x = 0, d/4, d/2, 3d/4, d$). The pink arrows indicate the azimuthal angular trajectory from the bottom to the top of the cell, which is also the light propagation direction. The 3° offset between the buffing and electrode orientations breaks the mirror symmetry about $E$, causing the n-P couple to rotate preferentially counterclockwise in response to $P \times E$ torques (white arrow in [B]). At $V_{IN} \sim 90 \ \text{mV} (E \sim 60 \ \text{mV/mm})$ in the gap center, the LH $\pi$T state appears in several places via heterogeneous nucleation, being the field preferred state since it has $P$ largely directed along $E$. The field tends to expel the LH twist to the surfaces, filling the cell center with the preferred orientation. The LT and RH $\pi$T states are separated by $2 \times$twist walls. The domain walls in E–H move readily in response to small increases in the applied field but the internal structure of the LH and RH states changes little in this voltage range. (I–K) Steady-state director profiles $\psi(x)$ of the LH and RH states calculated numerically by solving the fieldelastic torque balance equation given in the text, assuming fixed surface orientations at $\psi(0) = 48^\circ$ and $\psi(d) = 93^\circ$. (l) Uniformly twisted RH starting state in the absence of applied field. (l) Deformed RH state in presence of an $E$ field favoring $\psi = 180^\circ$. Because the buffing is not perpendicular to the applied field, and $P$ in the starting state in (l) has a component directed opposite $E$, there is a net counterclockwise reorientation of $P$ in the cell. (k) The field finally induces a transformation, shown schematically in Fig. 1E, from the RH to the LH twist state. The polarization profile, corresponding to the azimuthal angular trajectory sketched in (H), is plotted here with $\psi$ increasing downward. Inserts show the calculated transmitted hue of the model twist states between crossed polarizer and analyzer.
\[
q(t) = 2 \tan^{-1}\left[\frac{\tan(q_s(t)/2)}{\exp\left[-t(P/Ly)(V_{IN}/(P/C)\cos q(t) \cdot \exp[-(t/RC)]\right]}\right].
\]

Solving this equation for the effective relaxation time and varying the parameters \(C\) and \(RC\) to fit the ROT optical response measurements gives the dotted black curve in Fig. 3A, with \(RC = 100 \mu s\) and \(C = 0.15 \mu F/cm^2\). This result shows that for low \(E\), the response of the director field is sufficiently slow that the depolarization voltage across the barrier relaxes towards zero, allowing the full \(V_{IN}/L\) field to appear across the LC material, and yielding \(\tau_b = \gamma PE\) behavior. At intermediate fields, the insulating layer behaves like a capacitor and the applied voltage is divided between the insulating layer and the LC. When the field is applied, substantial reorientation occurs before the boundary charge can leak away, and the depolarization voltage competes with \(V_{IN}\) to reduce the effective field on the LC and substantially retard the relaxation. At the highest fields, we have \(V_{IN} \gg P/C\), and the relaxation time approaches \(1/E\) dependence again.

**Field Reversal (REV) Dynamics.** The response to applied field reversal is simulated by starting with the field-confined LH state that is the final configuration of the ROT process (solid black curves in Fig. 3D) and flipping the sign of \(E\). Immediately after field reversal, the entire center of the cell has \(P\) opposing the applied field, so that in most of the cell the polarization experiences zero torque from the field and thus does not respond. However, near the surfaces, where \(P\) reorients to the surface preference, there is an electrical torque so the response starts there, with the formation of solitons in the polarization field (Fig. 3B) that propagate toward the cell center at a velocity \(v = \varepsilon_0/\varepsilon_0\), reaching the center in the field reversal time \(\tau_R = d/2v \sim \tau_c(d/2\varepsilon_e)\) (43). The solitons then combine to form a thin sheet centered at \(x = d/2\) where the polarization makes a \(\Delta \phi = 2\pi\) reorientation between equivalent orientations of \(P\) aligned with the field. This sheet disappears via the topological processes of order reconstruction (44, 45), or the spontaneous appearance of twist disclination loops, either way changing the handedness to leave a field-confined RH \(\pi\)-twist configuration. The simulated reversal time \(\tau_R\) in the soliton regime, plotted as the upper solid white line in Fig. 3A, varies with \(E\) as \(\tau_R \propto E^{-1/2}\), decreasing more slowly with filed than the \(\tau_c \propto E^{-1}\) rotational response discussed previously. In our field range, \(\tau_R\) is noticeably larger than \(\tau_c\), a reflection of the time spent by the metastable interior of the cell with \(P\) at \(\varphi = 0\) waiting for the solitons to arrive.

Field-reversal dynamics have been probed experimentally by measuring the response of the twisted states in the cell of Fig. 2 to square-wave driving, as simulated in Fig. 3B. The optical response enables identification of the soliton propagation (baby pink) and topological transition (baby blue) stages of reorientation. The optical transmission through crossed polarizer/analyzer (parallel to \(E\)) vs. time following an applied voltage reversal at \(t = 0\) is shown in Fig. 3C. The transmission of the starting state is very low, with only the very thin, twisted surface regions depolarizing the light. The subsequent response, characterized by one or more peaks in the transmitted intensity, is identical for \(+/\)- and \(-/\)- reversals, indicating that a complete transition between LH and RH confined twist states is obtained at each reversal. As \(E\) is increased, the overall optical transmission due to the traveling solitons (baby pink arrows) gets smaller because the solitons become thinner (43). The arrival of the solitons in the cell center is heralded by a distinct peak in the transmission (Fig. 3B and C, white circles), produced by the transient, extended linear variation in \(q(t)\) about \(q(0) = 0\) near the center of the cell (white circles, Fig. 3B and C). This peak is directly followed by the order recombination that completes the transition to the final field-stabilized, nearly extinguishing state of opposite handedness (baby blue arrows). Once reorientation is complete, the baseline optical transmission is again very low, with only the confined regions at the cell surfaces depolarizing the light. The overall transition times \(\tau_R\) for this process, plotted vs. \(E\) in Fig. 3D (using dot colors that match the curve colors in Fig. 3C), are much longer than the measured rotation times \(\tau_c\). The simulations of Fig. 3B give similar \(\tau_R\) values (solid white line) with no adjustable parameters, just using the value of \(\gamma\) derived from the ROT data. Also plotted in Fig. 3D are the optical and polarization field-reversal 10-90% response times shown in Fig. 3C of ref. 14, obtained for square-wave driving but in different cell geometries (black dots). These response times are comparable to those of Fig. 3B and C, indicative of a retardation similar to that seen in solitonic field reversal. Interestingly, these individual sets of data all exhibit close to a \(\tau_R \propto E^{-1}\) dependence rather than the \(\tau_c \propto E^{-1/2}\) expected from the soliton model. This discrepancy may be due to the assumption in the model that in the beginning, away from the surfaces, there is perfect polar order, with \(P\) initially uniformly aligned by the field at \(\varphi = 0\). In this idealized situation, when the field reverses, each soliton must travel half the cell thickness \(d/2\) in order to switch the cell. In practice, however, due to defects, surface imperfections, and thermal fluctuations, \(P\) is only rarely perfectly aligned along \(\varphi = 0\) in the cell interior, and, once the field switches, experiences torques in many different locations and begins to reorient inhomogeneously. This process will proceed more rapidly as the field is increased, and will lead to the local nucleation and soliton-mediated growth of substantially reoriented domains dependent on the size and orientational deviation of nucleated domains (46). To the extent that such domains appear and expand, the net time for complete reversal is expected to decrease because the solitons will, on average, have less distance to cover. The experimentally observed \(\tau_R \propto E^{-1}\) behavior would imply a mean soliton travel distance decreasing with increasing \(E\) as \(E^{-1/2}\). The field-reversal data in Fig. 3D suggest that this may be universal behavior.

**Domain-Mediated Dynamics.** Generally, for small, in-plane applied \(E\), the LH and RH \(\pi\)-twist states will have different net energies of interaction with the field. As a result, if both twist states are present in a cell, the \(2\pi\)-twist wall boundaries between them move in the \(yz\)-plane to expand the area of those states with lower energy, or new lower-energy states will be nucleated. The creation or motion of these domain boundaries is inherently hysteretic, potentially enabling bistable electro-optic effects. An example of a \(2\pi\)-twist wall creation in a \(d = 3.5 \mu m\) ANTIPOLAR cell with in-plane ITO electrodes spaced by 1 mm is shown in Fig. 4. The field is weak (\(E < 0.3\) V/mm) and very slowly varying (\(\sim 0.1\) Hz). The significant, continuous distortion of the original RH \(\pi T\) state with increasing field is punctuated by the nucleation and growth of less distorted LH \(\pi T\) domains, which eventually take over the whole cell area and which remain after \(E\) is returned to zero. The field direction in this cell is offset by 3 degrees from the bisection of the antiparallel buffing directions, ultimately favoring the global counterclockwise reorientation of \(P\) (see profile in Fig. 4J). As a result, the \(2\pi\)-twist walls separating the LH domains mutually annihilate on contact and disappear as the LH area grows.

**Discussion**

**Nematic and Ferroelectric Nematic Textures.** LCs feature a remarkable combination of fluidity and order, which manifests itself in their uniquely facile macroscopic response to surfaces. In thin cells between flat plates, the bulk LC organization is strongly affected by surface interactions, leading to the formation of specific textures, bulk structural themes on the micrometer-to-millimeter scale that reflect the balance of surface, field, and elastic energies. Analysis of these textures, typically using DTLM, enables the study both of surface alignment characteristics and of key bulk LC properties like phase behavior, elasticity, and symmetry. Friedel’s discovery of smectics is the classic example of this investigative approach (47). If the orientational preferences on the two surfaces of a cell...
are different, then generally each preference should be manifest somehow in the bulk, either in any given cell, or as a statistical average over the LC organization in many cells. For example, in a hybrid-aligned cell, where one side prefers \( n \) normal to the surface and the other \( n \) parallel, the observed splay-bend nematic texture simultaneously satisfies both surface preferences. If the two surfaces are equivalent in structure but differ in preferred orientation (rubbed in perpendicular directions, for example), then the different surface preferences must be expressed equivalently in the bulk LC in some fashion, as they indeed are in the 90° twisted texture that forms in a nematic. A planar-aligned smectic, on the other hand, may accommodate the surfaces in such a 90°-rubbed cell by forming homogeneous domains that locally fill the cell, with some domains following the 0° surface and others following the 90° surface, with areas that are equal when averaged over many cells. This brings us to cells of the \( N_F \) phase, in which, new to LC alignment physics, a similar condition appears for the polar ordering at the surfaces. If the surfaces are structurally identical but differ in polar orientation, then the competing polar orientations must be equivalently expressed in the cell texture. The first definitive examples of such behavior in nematics are the \( \pi T \) states of opposite handedness in the \textit{ANTIPOLAR} \( N_F \) cells of Figs. 1 and 2. These twisted states have distributions in azimuthal orientation that are symmetric about \( \phi = \pi/2 \), thus accommodating the competing polar surface orientations of the two cell surfaces. This scenario is achieved by growth in a temperature gradient of the \( N_F \) from one surface leading to the formation of a PPR wall at the other surface, which becomes unstable at lower temperature, leading in turn to the formation of a uniformly twisted state. Cooling without a gradient leads to PPR formation in the cell interior, as in Figs. 1F and 2H, giving a uniform director field with a PPR wall parallel to the cell plates that effects a transition between the two surface preferences. This kind of growth could lead to the formation of arrays of twist domains with different surface preference. The transition to the twisted state in Fig. 2C is barrier-limited so the PPR wall may be stable or metastable, depending on its energy cost relative to that of the uniformly twisted state. When cooling without a gradient, \( N_N \) surfaces enter move into the cell from both surfaces and may interact with one another. For example, thermal interactions could lead to a coupled Mullins–Sekerka instability (1), as the approach of one interface releasing heat will slow the advance of the other.

**Solvent Poling.** The bulk ferroelectric nematic LC can be thought of as a polar medium described by the continuous unit vector field \( \mathbf{v}(r) = P(r) / |P| \), the 3D structure of which is determined by the Frank elasticity, the electrostatic self-energy, and interactions with its bounding surfaces. Such a 3D polar medium can, in turn, act as a 3D polar medium can, in turn, act as a vectorial solvent, locally orienting polar solute molecules along \( \mathbf{v}(r) \). This would constitute poling by the solvent, in contrast to the typical approach of field poling in a solvent (e.g., in a polymer thermostet) (48). Ferroelectric nematics are extremely unusual solvents owing to their fluidity, high degree of polar orientational order, and record-large, liquid-state ferroelectric polarization. The lack of mirror reflection symmetry along \( P \) guarantees some degree of induced polarity in any solute molecule, but dipolar solutes, in particular, immersed in the \( \text{RM734} \) \( N_F \) phase find themselves in a highly polarizing environment. The pair correlation functions from our atomistic simulations (14) show that the mean \( E \) field experienced by each molecule due to its neighbors in the \( N_F \) phase is of the order \( E_{\text{loc}} \sim 10^9 \text{ V/m} \), parallel to \( P \). This is effectively a poling field, creating a \( \sim 10 \text{kT} \) barrier that orientationally pins the dipoles of individual \( \text{RM734} \) molecules, or of single, similarly dipolar solute molecules in \( \text{RM734} \), parallel to \( P \) on average. Thus, for molecules with appropriate steric and dipolar structure (such as rod-like molecules with large, longitudinal dipole moments), \( v(r) \) is effectively a strongly aligning field ultimately controlled by the orientational preferences of the surfaces. In summary, we have shown that in the ferroelectric nematic, surface polarity plays a key role in providing coupling to a macroscopic field variable. Polarity normal to the bounding surfaces is inherent, but must be brought under control to be useful in \( N_F \) materials. In-plane polarity will result from any surface treatment, e.g., coating, deposition, etching, or illumination, that locally breaks mirror symmetry about some plane normal to the surface. Finally, in order for studies of the optical behavior of other behavior of ferroelectric nematics to be interpretable, the polar alignment characteristics of the bounding surfaces must be specified, understood, and reported.

**Materials and Methods**

**Synthesis of \( \text{RM734} \).** 4-((4-Nitrophenoxy)carbonyl)phenyl 2,4-dimethoxybenzoate (\( \text{RM734} \)) is a rod-shaped mesogen first synthesized by Mandle et al. (10). It was reported to have an isotropic (I) phase and two additional phases with nematic character, with transition temperatures as follows: I \( \rightarrow \) 187 °C \( \rightarrow \) N \( \rightarrow \) 133 °C \( \rightarrow \) \( \pi \) \( \rightarrow \) X. Our preparation gives transition temperatures as follows: I \( \rightarrow \) 188 °C \( \rightarrow \) N \( \rightarrow \) 133 °C \( \rightarrow \) \( \pi \) \( \rightarrow \) X (14).

**Observations of Response to Applied Electric Field.** Experimental cells were made by filling LC samples between glass plates spaced to a desired gap, \( d \). The plates were coated with lithographically patterned ITO or gold electrodes for application of in-plane electric fields. Cells with unidirectionally buffered alignment layers were obtained from Instec Inc. Electro-optic observations were carried out with cells mounted on the rotary stage of a polarizing light microscope and imaged in transmission. Temperature control was maintained using an Instec hot stage.

**Data Availability.** Data, simulations, and videos have been deposited in the Open Science Framework (OSF) database Ferroelectric nematic (DOI: 10.17605/osf.io/ZKFTW).

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